



The products are transistor opto-couplers in a SSOP4 package. The device is a photoelectric coupler composed of light-emitting diode and phototransistor. The products are widely used in switching power supply, intelligent meter, industrial control, measuring instruments, office equipment such as copiers, household appliances: such as air conditioners, fans, water heaters, etc.

High isolation 3750 VRMS

Operating temperature range -40°C to 125°C

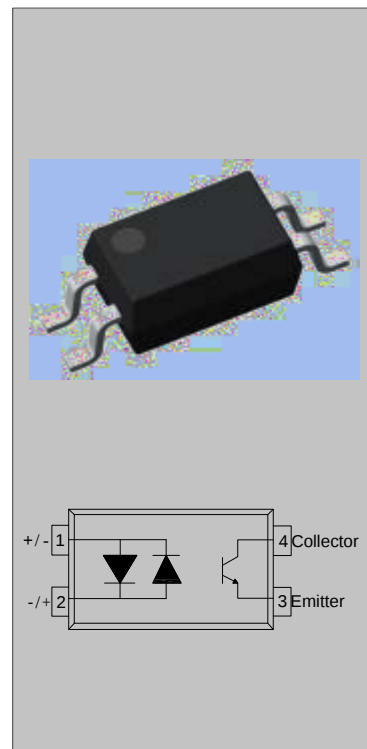
RoHS & REACH Compliance

HBM: H3A; MM: M4; CDM:C3

CQC approved

VDE approved

UL approved



(Temperature=25°C)

Parameter		Symbol	Value	Unit
Input	Forward Current	I_F	± 50	mA
	Peak Forward Current	I_{FP}	1	A
	Power Dissipation	P_D	75	mW
Output	Collector-emitter Voltage	V_{CEO}	80	V
	Emitter-collector Voltage	V_{ECO}	7	V
	Collector Current	I_C	50	mA
	Power Dissipation	P_C	150	mW
Total Power Dissipation		P_{tot}	225	mW
Isolation Voltage		V_{iso}	3750	Vrms
Operating Temperature		T_{opr}	-40~+125	
Junction Temperature		T_j	135	
Storage Temperature		T_{stg}	-55~+125	
Soldering Temperature		T_{sol}	260	

: 1 μ s pulse

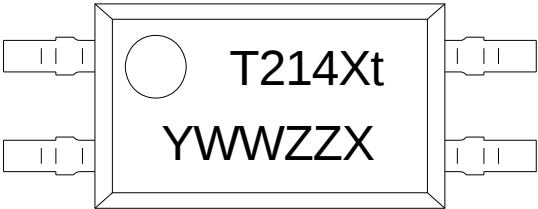
: AC for 1minute, R.H.=40~60%

(Temperature=25°C)

Parameter		Symbol	Condition	Min.	Typ.	Max.	Unit
Input	Forward Voltage	V_F	$I_F=\pm 10\text{mA}$	-	1.2	1.5	V
	Terminal Capacitance	C_t	$V=0$, $f=1\text{MHz}$	-	30	250	pF
Output	Collector-Emitter dark current	I_{CEO}	$V_{CE}=20\text{V}$, $I_F=0$	-	-	50	nA
	Collector-Emitter breakdown voltage	BV_{CEO}	$I_C=0.1\text{mA}$ $I_F=0$	80	-	-	V
	Emitter-Collector breakdown voltage	BV_{ECO}	$I_E=0.1\text{mA}$ $I_F=0$	7	-	-	V
Transfer Characteristics	Current transfer ratio	CTR	$I_F=\pm 5\text{mA}$ $V_{CE}=5\text{V}$	100	-	400	%
	Collector-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_F=\pm 10\text{mA}$ $I_C=1\text{mA}$	-	0.07	0.2	V
	Isolation resistance	R_{IO}	DC500V 40~60%R.H.	5×10^{10}	10^{11}	-	Ω
	Floating Capacitance	C_{IO}	$V=0$, $f=1\text{MHz}$	-	0.3	1	pF
	Cut-off Frequency	f_c	$V_{CE}=5\text{V}$, $I_C=2\text{mA}$ $R_L=100\Omega$, -3dB	-	80	-	kHz
	Rise Time	t_r	$V_{CE}=2\text{V}$, $I_C=2\text{mA}$ $R_L=100\Omega$	-	4	18	μs
	Fall Time	t_f		-	3	18	μs
	Response Time	t_{on}		-	9	25	μs
		t_{off}		-	5	25	μs

J	OC	T	214	P	t	-S4	/
JieJie Microelectronics Co., Ltd.	Opto Coupler	Transistor	Marketization Model	CTR Rank:P/Q	t:High Temperature	SSOP4	None:T1 R:T2

None/R	3000 Units/Reel



LOT NO.

FIG.1: Max. Allowable LED Forward Current vs. Ambient Temperature

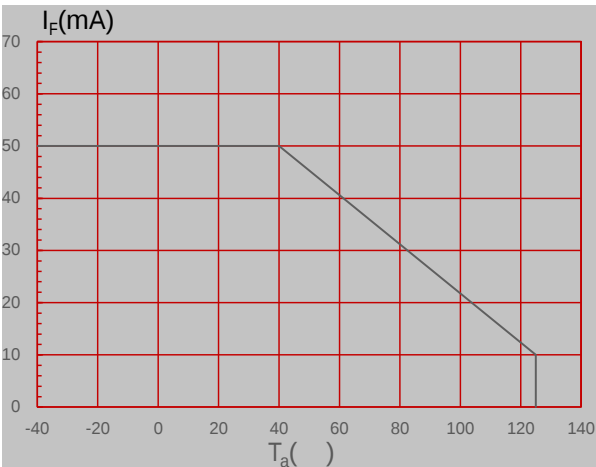


FIG.2: Collector Power Dissipation vs. Ambient Temperature

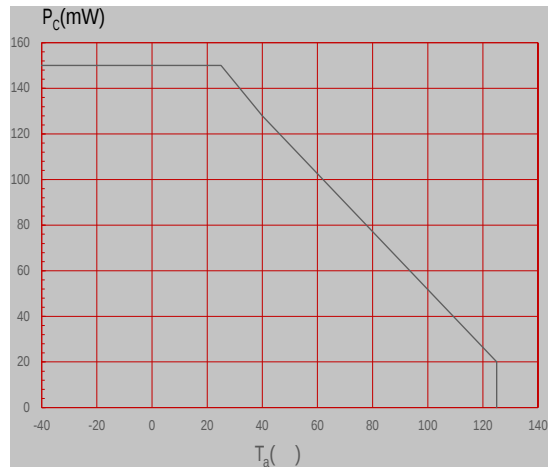


FIG.3: Forward Current vs. Forward Voltage

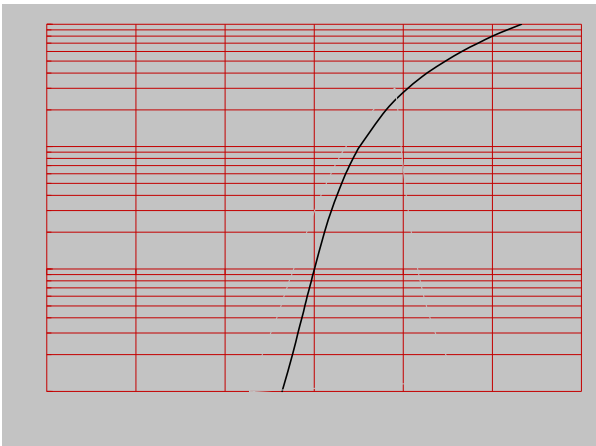
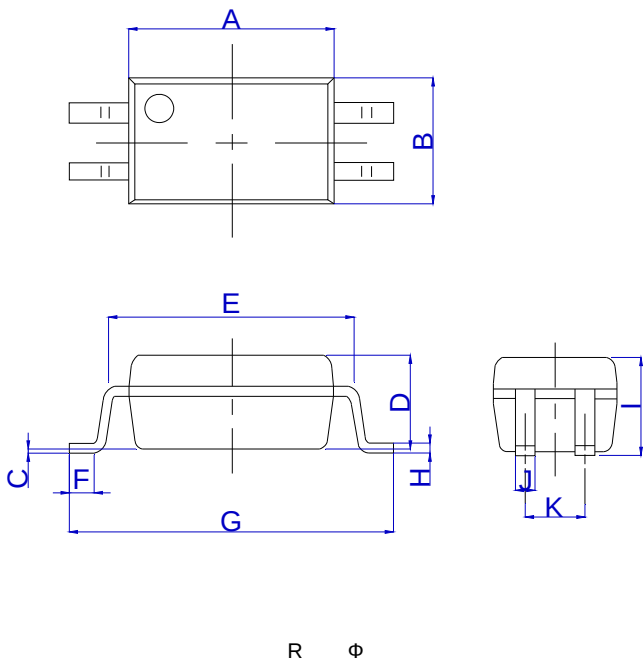
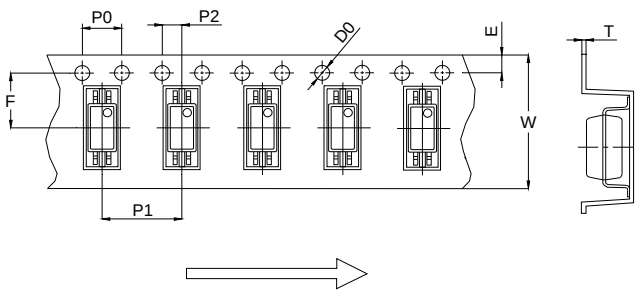


FIG.4: Normalized Collector Dark Current vs. Ambient Temperature

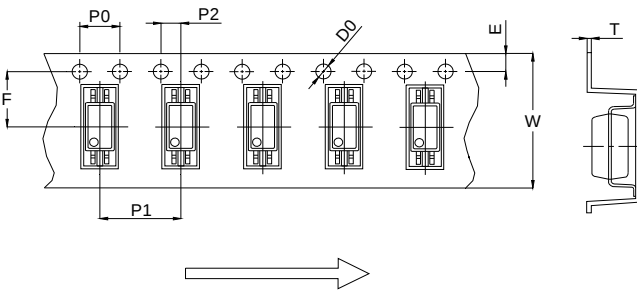


Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A						
B						
C						
D						
E						
F	0.39			0.015		
G						
H						
I	1.88					
J						

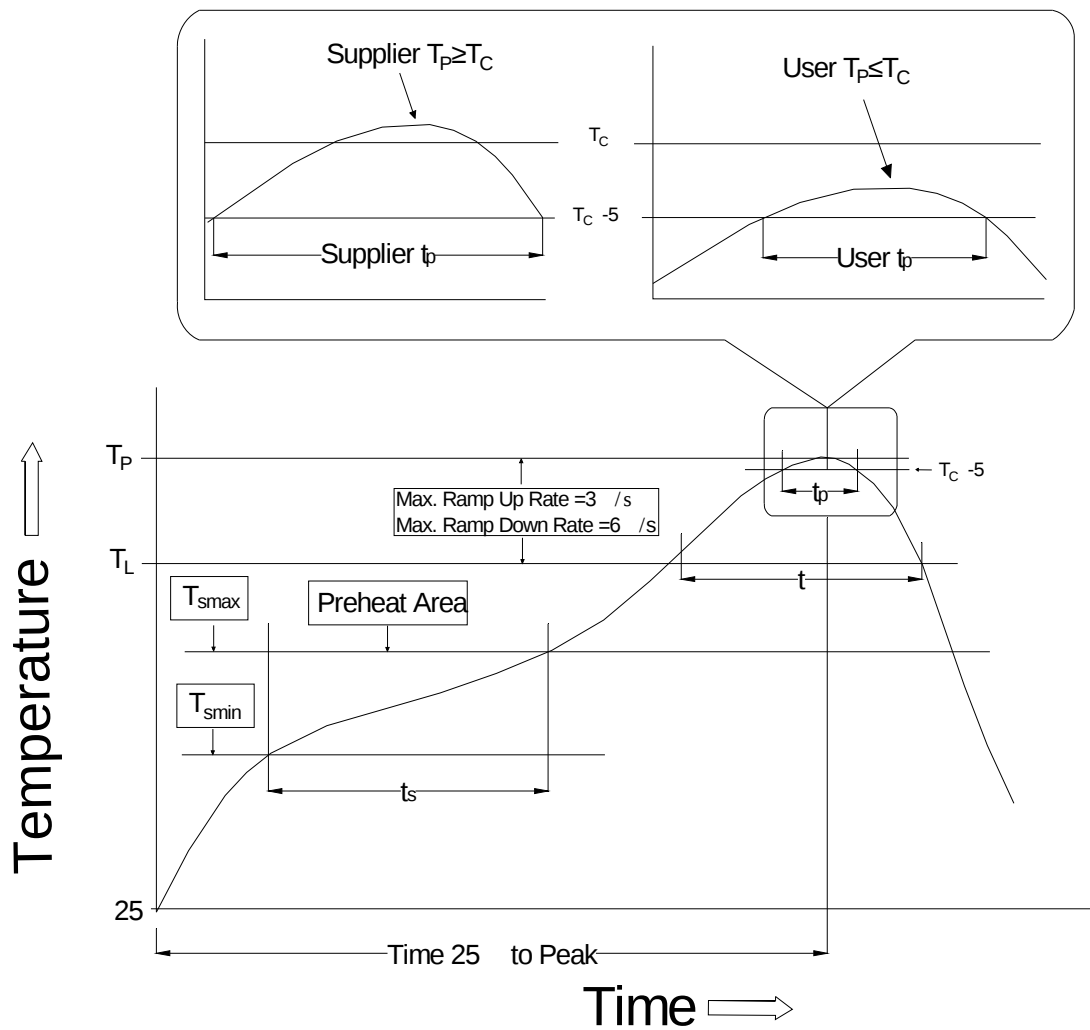
R



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.50	1.60		0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	5.40	5.50	5.60	0.213	0.217	0.220
T	0.20	0.25	0.30	0.008	0.010	0.012
W	11.90	12.10	12.30	0.469	0.476	0.484



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
D0		1.50	1.60		0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
E	1.65	1.75	1.85	0.065	0.069	0.073
F	5.40	5.50	5.60	0.213	0.217	0.220
T	0.20	0.25	0.30	0.008	0.010	0.012
W	11.90	12.10	12.30	0.469	0.476	0.484



Profile Feature	Sn-Pb Assembly Profile	Pb-Free Assembly Profile
Temperature Min. (T_{smin})	100	150
Temperature Max. (T_{smax})	150	200
Time (t_s) from (T_{smin} to T_{smax})	60-120 seconds	60-120 seconds
Ramp-up Rate (t_L to t_P)	3 °C/second max.	3 °C/second max.
Liquidus Temperature (T_L)	183	217
Time (t_L) Maintained Above (T_L)	60-150 seconds	60-150 seconds
Peak Body Package Temperature	235 +0 /-5	260 +0 /-5
Time (t_P) within 5 °C of 260	20 seconds	30 seconds
Ramp-down Rate (T_P to T_L)	6 °C/second max.	6 °C/second max.
Time 25 °C to Peak Temperature	6 minutes max.	8 minutes max.

Note:

1. Reflow soldering is recommended at the temperatures and times shown, no more than three times.
2. Avoid direct contact between the epoxy body and any tools or surfaces exceeding its maximum storage temperature.
3. Application of pressure on the epoxy body is prohibited at elevated temperatures. In specific scenarios, any applied force must not exceed 2.5N.
4. Ensure the component has cooled to ambient temperature before proceeding with any subsequent manufacturing steps.
5. The component has a shelf life of one year when stored under standard conditions.
6. Recommend storage Temp.: 0~40°C;
Recommend storage humidity: <60%;
MSL level: MSL 1

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